

MOSFETs Silicon N-Channel MOS (U-MOSVI-H)

TK50P04M1

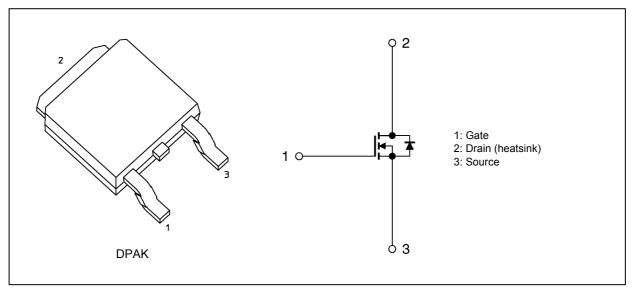
1. Applications

- Switching Voltage Regulators
- · Motor Drivers
- · Power Management Switches

2. Features

- (1) High-speed switching
- (2) Low gate charge: $Q_{SW} = 9.4 \text{ nC (typ.)}$
- (3) Low drain-source on-resistance: $R_{DS(ON)} = 6.7 \text{ m}\Omega$ (typ.) ($V_{GS} = 10 \text{ V}$)
- (4) Low leakage current: $I_{\rm DSS}$ = 10 μA (max) (V_{DS} = 40 V)
- (5) Enhancement mode: $V_{th} = 1.3 \text{ to } 2.3 \text{ V (V}_{DS} = 10 \text{ V}, I_D = 0.5 \text{ mA)}$

3. Packaging and Internal Circuit





4. Absolute Maximum Ratings (Note) (Ta = 25°C unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	40	V
Gate-source voltage			V_{GSS}	±20	
Drain current (DC)		(Note 1)	I _D	50	Α
Drain current (pulsed)		(Note 1)	I _{DP}	150	
Power dissipation	(T _c = 25°C)		P_D	60	W
Single-pulse avalanche energy		(Note 2)	E _{AS}	65	mJ
Single-pulse avalanche current			I _{AS}	50	Α
Channel temperature			T _{ch}	150	ç
Storage temperature			T _{stg}	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	R _{th(ch-c)}	2.08	°C/W
Channel-to-ambient thermal resistance	R _{th(ch-a)}	125	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 32 V, T_{ch} = 25°C (initial), L = 20 μ H, R_G = 1.2 Ω , I_{AS} = 50 A

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.



6. Electrical Characteristics

6.1. Static Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0 \text{ V}$	_		±0.1	μА
Drain cut-off current	I _{DSS}	V _{DS} = 40 V, V _{GS} = 0 V	_	_	10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = 10 mA, V _{GS} = 0 V	40		_	V
	V _{(BR)DSX}	I _D = 10 mA, V _{GS} = -20 V	25		_	
Gate threshold voltage	V_{th}	V _{DS} = 10 V, I _D = 0.5 mA	1.3	_	2.3	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = 4.5 V, I _D = 25 A		7.8	10.2	mΩ
		V _{GS} = 10 V, I _D = 25 A	_	6.7	8.7	

6.2. Dynamic Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	2600		pF
Reverse transfer capacitance	C _{rss}			110		
Output capacitance	C _{oss}			420		
Gate resistance	r _g	V _{DS} = 10 V, V _{GS} = 0 V, f = 5 MHz	_	2.5	3.8	Ω
Switching time (rise time)	t _r	See Figure 6.2.1.		22		ns
Switching time (turn-on time)	t _{on}			29		
Switching time (fall time)	t _f		_	10		
Switching time (turn-off time)	t _{off}		_	77	_	

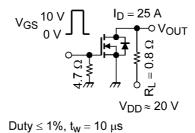


Fig. 6.2.1 Switching Time Test Circuit

6.3. Gate Charge Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus	Q_g	$V_{DD} \approx 32 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 50 \text{ A}$	_	38		nC
gate-drain)		$V_{DD} \approx 32 \text{ V}, V_{GS} = 5 \text{ V}, I_D = 50 \text{ A}$	_	20		
Gate-source charge 1	Q _{gs1}	$V_{DD} \approx 32 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 50 \text{ A}$	_	8.0		
Gate-drain charge	Q_{gd}		_	5.7		
Gate switch charge	Q_SW		_	9.4		

6.4. Source-Drain Characteristics (T_a = 25°C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note 3)	I _{DRP}	_	_	_	150	Α
Diode forward voltage	V _{DSF}	I _{DR} = 50 A, V _{GS} = 0 V	_	_	-1.2	V

Note 3: Ensure that the channel temperature does not exceed 150°C.



7. Marking

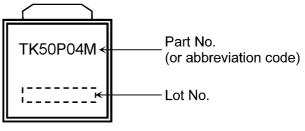
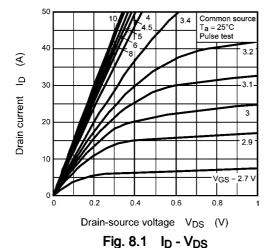
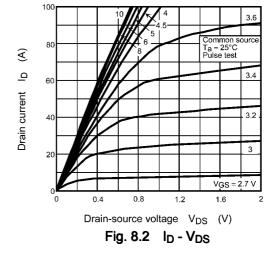
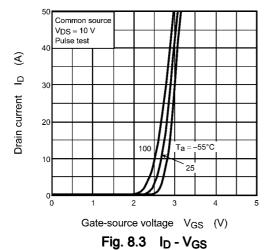


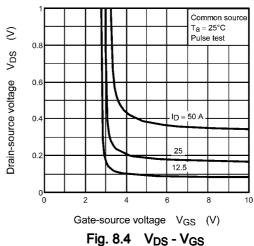
Fig. 7.1 Marking

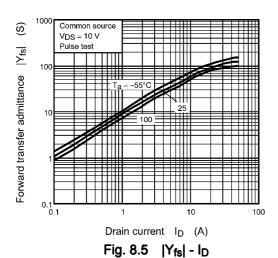
8. Characteristics Curves (Note)











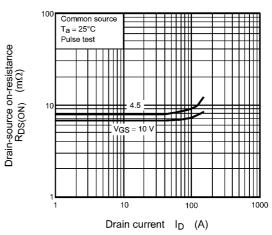
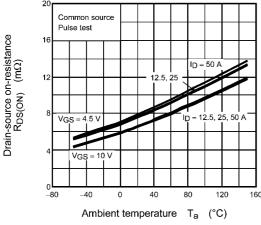
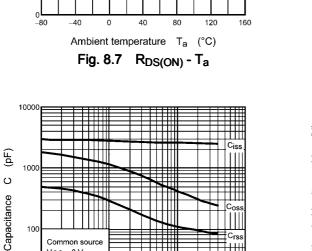


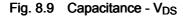
Fig. 8.6 R_{DS(ON)} - I_D





Drain-source voltage V_{DS} (V)

VGS = 0 V f = 1 MHz $T_a = 25$ °C



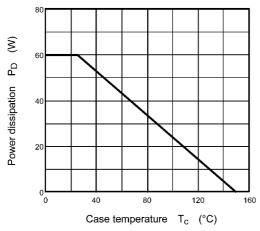


Fig. 8.11 P_D - T_c (Guaranteed Maximum)

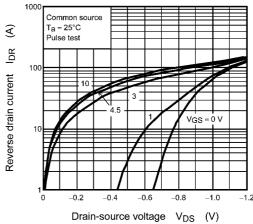


Fig. 8.8 I_{DR} - V_{DS}

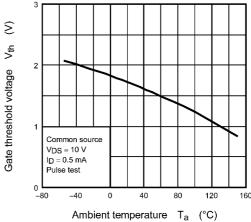


Fig. 8.10 V_{th} - T_a

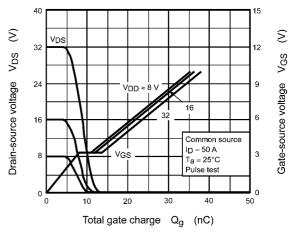


Fig. 8.12 Dynamic Input/Output Characteristics

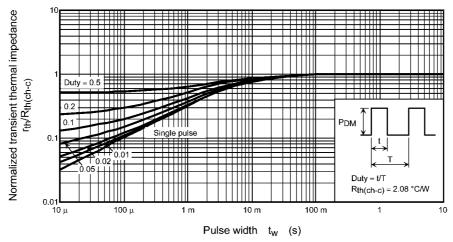


Fig. 8.13 $r_{th}/R_{th(ch-c)} - t_w$ (Guaranteed Maximum)

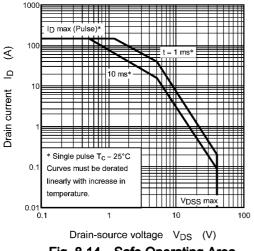


Fig. 8.14 Safe Operating Area (Guaranteed Maximum)

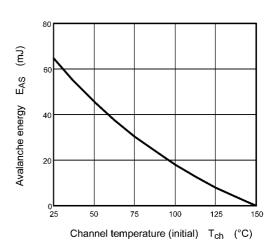


Fig. 8.15 E_{AS} - T_{ch} (Guaranteed Maximum)

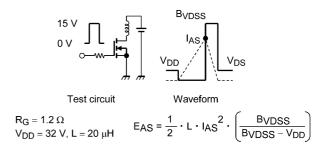


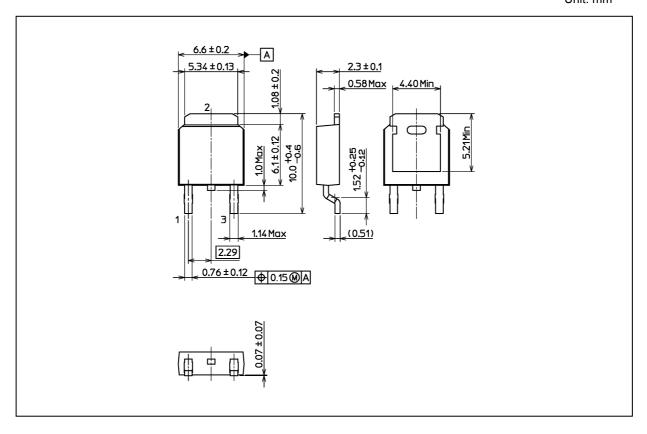
Fig. 8.16 Test Circuit/Waveform

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 0.36 g (typ.)

	Package Name(s)
TOSHIBA: 2-7K1S	
Nickname: DPAK	



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